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See General Information for Electrically-isolated Semiconductor Devices - Component

EUPEC GMBH & CO KG E83336

MAX-PLANCK-STRASSE 5 POSTFACH 2340 59581 WARSTEIN-BELECKE, GERMANY

20 mm solder DCB modules, Type DD followed by 31, 55, 61, 76, 90 or 105; Type DT, TD or TT followed by 18, 25, 31, 36, 46, 56, 66, 93 or 105, may be followed by additional letters and/or numbers.

42 mm solder DCB module, Type DDBfollowed by 6, followed by U, followed by 85, 145 or 205, followed by N.

54 mm solder DCB modules, Type TDB followed by 6, followed by HK, followed by 95, 135 or 165, followed by N; Type TDM followed by 3, followed by U, followed by 135 followed by N; Type TTB followed by 6, followed by C, followed by 95, 135 or 165, followed by N; Type TTW followed by 3, followed by C, followed by 85, 115 or 145, followed by N.

62 mm transistor modules, Cat. No. BSM or BYM followed by 05 thru 600; followed by A, GA, GB, GD, GM, GP, GT, GAL, GAR or GDAL, followed by 60 thru 180, may be followed by other letters and or numbers; Cat. No. BSM followed by 15, 25 or 30, followed by GP, followed by 60 or 120; Cat. No. DF, FD, FP, FF, FS, F4 or FZ followed by 15 thru 800, followed by R, followed by 06, 12 or 17, may be followed by other letters; Cat. No. FS followed by 25, 35, 50, 75, 100 or 150, followed by R, followed by KE, followed by 3, may be followed by G.

Type "EconoPACK" and "EconoDUAL", Cat. No. FF, DD, FD, DF, FP or FS followed by 50 thru 600, followed by R, followed by 06 thru 17, may be followed by alpha-numeric digits.

Electrically-isolated semiconductor devices, Models IHM and IHV Modules, Cat. Nos. DD, FD, FF, FS, FZ, DZ, DF or F4, followed by 8 through 3600, followed by R, S or A followed by 06 through 65, may followed by additional numbers and/or letters. Model PrimePACK, Cat. Nos. DD, FD, FF, FS, FZ, DZ, DF or F4, followed by 8 through 3600, followed by R, S or A followed by 06 through 33, may followed by additional numbers and/or letters.

Gate turn-off devices, Cat. Nos. DG50A, -50R, -90A, -90R, -150A, -150R, GD50A, -50R, -90A, -90R, -150A, -

ISO pack bridge rectifier, Cat. No. DDB6U, TDB6HK, TDM3U, TDW3H, TTB6C or TTW3C followed by 85 thru 215, followed by additional letters and or numbers.

ISOPACK module, Cat. No. DDB6U followed by 84N, 100N or 144N, followed by additional number and/or letters.

Mosfet half bridge semitrna M2 (dual), Cat. Nos. BSM 204 A, BSM 214 A, BSM 224 A, BSM 225 A, BSM 244 F, BSM 254 F, BSM 284 F, BSM 294 F.

Mosfet single switch semitrans M1 (single), Cat. No. BSM or BYM followed by 10, 15, 25, 30, 35, 50, 75, 100, 150, 200, 300, 400 or 600, followed by A, GA, GAL, GAR, GB, GD or GM, followed by 060, 100, 120, 160 or 170, may be followed by D and/or other numbers or letters; Cat. No. BSM1 followed by 0, 1, 2, 3, 4, 5, 8 or 9, followed by 0 or 1, may be followed by AR, C, F, H, L or R; Cat. No. BSM2 followed by 0, 1, 2, 4, 5, 8 or 9, followed by 2 or 4, may be followed by A or F; Cat. Nos. BSM 101 AR, BSM 111 AR, BSM 121 AR, BSM 141, BSM 151, BSM 151 F, BSM 181, BSM 181 R, BSM 191, BSM 191 F, SIMOPAC.

Power block 20 mm, Cat No. AD, ADR, DD, DD, DD, ND, ND, NT, TD or TT followed by 32 thru 106, followed by additional letters and or numbers.

Power block 25 mm, Cat. No. DD, DO, DT, ND, TD or TT followed by 50 thru 106, followed by additional letters and/or numbers.

Power block 30 mm, Cat. No. AD, ADR, DD, DT, TD or TT followed by 71 thru 151, followed by additional letters and/or numbers.

Power block 34 mm, Cat. No. AD, ADR, DD, DO, DT, TD or TT followed by 96 thru 172, followed by additional letters and/or numbers; Cat. No. ND171N.

Cat. No. AD, ADR, DD, DO, DT, ND, TD or TT followed by 96 thru 172, followed by additional letters and/or numbers.

Power block 50 mm, Cat No. AD, ADR, DAX, DD, DO, DT, DZ, ND, TD, TT or TZ followed by 150 thru 600, followed by additional letters and or numbers; Cat. Nos. DT(D358S+T358S), TD(T358S+D358S)

Power block 60 mmCat. No. DD, DT, DZ, ND, NT, TD or TT followed by 180 thru 600, followed by additional letters and/or numbers.

Power blocks 70 mm, Type DZ 1070 followed by N, followed by 18, may be followed by additional numbers and/or letters, followed by 24; Type TZ800 followed by N, followed by 12, 16 or 18, may be followed by additional numbers and/or letters, followed by 18.

Power rectifiers, Cat. Nos.DDB, TDB, TDW, TTB, TTW followed by HK or U, followed by 04 thru 600, may be followed by additional numbers or letters.

Power switching semi-conductors, Easy modules, Cat. No. FB, FP, FC, F4, FF, FZ or FS followed by 04 thru 600, followed by R followed by 06 or 12, may be followed by other numbers or letters; Cat. Nos. FP10R06KL4B3ENG, FP15R12WT3ENG.

Power switching semiconductor, "High power modules", IHM/IHV Series, Types DD, FD, FF, FS, FZ, DZ, DF or F4 followed by 8 thru 3600, followed by A, R or S, followed by 06 thru 65, followed by additional numbers and or letters.

Power transistor modules with 2500 v isolated heat sink, Cat. Nos. CC 50 R 600 K, CC 75 R 600 K, C 200 R 600 K, C 300 R 600 K, CC 300 R 1000 K, CC 100 R 1000 K, CC 150 R 1000 K, CC 100 R 1000 K, CC 200 R 1000 K, C 300 R 1000, CC 50 R 1200 K, CC 75 R 1200 K, CC 100 R 1200 K, CC 150 R 1200 K, CC 300 R 1200 K, CC 300 R 1200 K, FF 50 R 500 K, FF 50 R 500 K, FF 50 R 1000 K, FF 50 R 10

SCR's Type M followed by DD, DT, TD or TT, followed by two numbers, followed by a letter, followed by two numbers, followed by F or N.

Type THY followed by DM, L or M, followed by two numbers, followed by a letter, followed by numbers; Types DIL-74A, -78A.

Solder contact device, Cat. No. DD, DO, DT, ND, RR, TD or TT followed by 15 thru 105, followed by additional letters and or numbers.

Semitrans 2 (dual), Cat. Nos. BSM 25 GB 120 DN2, BSM 35 GB 120 DN2, BSM 50 GB 120 DN2, BSM 50 GAL 120 DN2, BSM 75 GAL 120 DN2, BSM 75 GAL 120 DN2K, BSM 100 GBL 120 DN2K, BSM 100 GAL 120 DN2K, BSM 50 GBL 170 DN2.

Semitrans 3 (dual), Cat. Nos. BSM 100 GB 120 DN2, BSM 100 GAL 120 DN2, BSM 150 GAL 120 DN2, BSM 150 GB 120 DN2, BSM 150 GB 120 DN2-E3166, BSM 25 GAL 120 DN2, BSM 150 GAL 120 DN2-E3166, BSM 200 GAL 120 DN2, BSM 200 GB 120 DN2, BSM 100 GB 170 DN2, BSM 150 GB 170 DN2-E3166, BSM 400 GB 60 DN2.

Semitrans 4 (1 diode only), Cat. Nos. BYM 300 A 120 DN2, BYM 300 A 170 DN2, BYM 600 A 170 DN2.

Semitrans 4 (single), Cat. Nos. BSM 200 GA 120 DN2, BSM 200 GA 120 DN2S, BSM 300 GA 120 DN2, BSM 300 GA 120 DN2-E3166, BSM 400 GA 120 DN2, BSM 400 GA 120 DN2S, BSM 200 GA 170 DN2, BSM 200 GA 170 DN2S, BSM 300 GA 170 DN2-E3166.

Semitrans IGBT sixpack, Cat. Nos. BSM 15 GD 120 D2, BSM 25 GD 120 D2, BSM 35 GD 120 D2, BSM 50 GD 120 D2.

NOTE: All catalog numbers may be followed by additional numbers and/or letters for manufacturer's identification purposes only.

Marking: The manufacturer's name or trademark and model or catalog number. <u>Last Updated</u> on 2007-05-03

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